

GENERAL DESCRIPTION

The 843011 is a Fibre Channel Clock Generator. The 843011 uses a 26.5625MHz crystal to synthesize 106.25MHz or a 25MHz crystal to synthesize 100MHz. The 843011 has excellent <1ps phase jitter performance, over the 637kHz – 10MHz integration range. The 843011 is packaged in a small 8-pin TSSOP, making it ideal for use in systems with limited board space.

FEATURES

- One differential 3.3V LVPECL output
- Crystal oscillator interface designed for 26.5625MHz 18pF parallel resonant crystal
- Output frequency: 106.25MHz or 100MHz
- VCO range: 560MHz - 680MHz
- RMS phase jitter @ 100MHz, using a 25MHz crystal (637kHz - 10MHz): 0.80ps (typical)
- RMS phase noise at 106.25MHz

Phase noise:

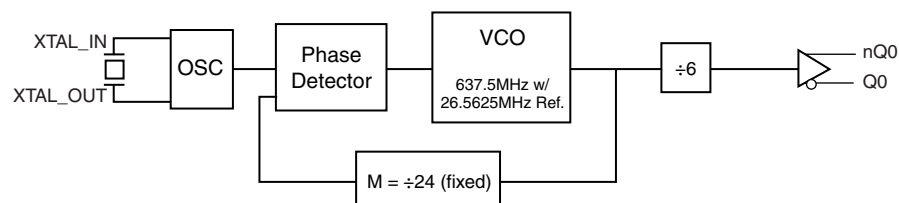
Offset	Noise Power
100Hz	-92.8 dBc/Hz
1kHz	-119.6 dBc/Hz
10kHz	-129.5 dBc/Hz
100kHz	-130.5 dBc/Hz

- 3.3V operating supply
- Available in lead-free (RoHS 6) package
- -40°C to 85°C ambient operating temperature

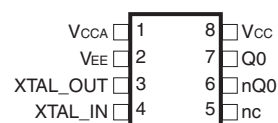
FREQUENCY TABLE

Crystal (MHz)	Output Frequency (MHz)
26.5625	106.25
25	100

BLOCK DIAGRAM



PIN ASSIGNMENT



843011

8-Lead TSSOP

4.40mm x 3.0mm x 0.925mm package body

G Package

Top View

TABLE 1. PIN DESCRIPTIONS

Number	Name	Type	Description
1	V _{CCA}	Power	Analog supply pin.
2	V _{EE}	Power	Negative supply pin.
3, 4	XTAL_OUT, XTAL_IN	Input	Crystal oscillator interface. XTAL_IN is the input, XTAL_OUT is the output.
5	nc	Unused	No connect.
6, 7	nQ0, Q0	Output	Differential clock outputs. LVPECL interface levels.
8	V _{CC}	Power	Core supply pin.

TABLE 2. PIN CHARACTERISTICS

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
C _{IN}	Input Capacitance			4		pF

ABSOLUTE MAXIMUM RATINGS

Supply Voltage, V_{CC}	4.6V
Inputs, V_I	-0.5V to $V_{CC} + 0.5V$
Outputs, I_O	
Continuous Current	50mA
Surge Current	100mA
Package Thermal Impedance, θ_{JA}	101.7°C/W (0 mps)
Storage Temperature, T_{STG}	-65°C to 150°C

NOTE: Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These ratings are stress specifications only. Functional operation of product at these conditions or any conditions beyond those listed in the *DC Characteristics* or *AC Characteristics* is not implied. Exposure to absolute maximum rating conditions for extended periods may affect product reliability.

TABLE 3A. POWER SUPPLY DC CHARACTERISTICS, $V_{CC} = 3.3V \pm 5\%$, $T_A = -40^\circ\text{C}$ TO 85°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V_{CC}	Core Supply Voltage		3.135	3.3	3.465	V
V_{CCA}	Analog Supply Voltage		3.135	3.3	3.465	V
I_{CCA}	Analog Supply Current	included in I_{EE}			12	mA
I_{EE}	Power Supply Current				93	mA

TABLE 3B. LVPECL DC CHARACTERISTICS, $V_{CC} = 3.3V \pm 5\%$, $T_A = -40^\circ\text{C}$ TO 85°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V_{OH}	Output High Voltage; NOTE 1		$V_{CC} - 1.4$		$V_{CC} - 0.9$	V
V_{OL}	Output Low Voltage; NOTE 1		$V_{CC} - 2.0$		$V_{CC} - 1.7$	V
V_{SWING}	Peak-to-Peak Output Voltage Swing		0.6		1.0	V

NOTE 1: Outputs terminated with 50Ω to $V_{CC} - 2V$.

TABLE 4. CRYSTAL CHARACTERISTICS

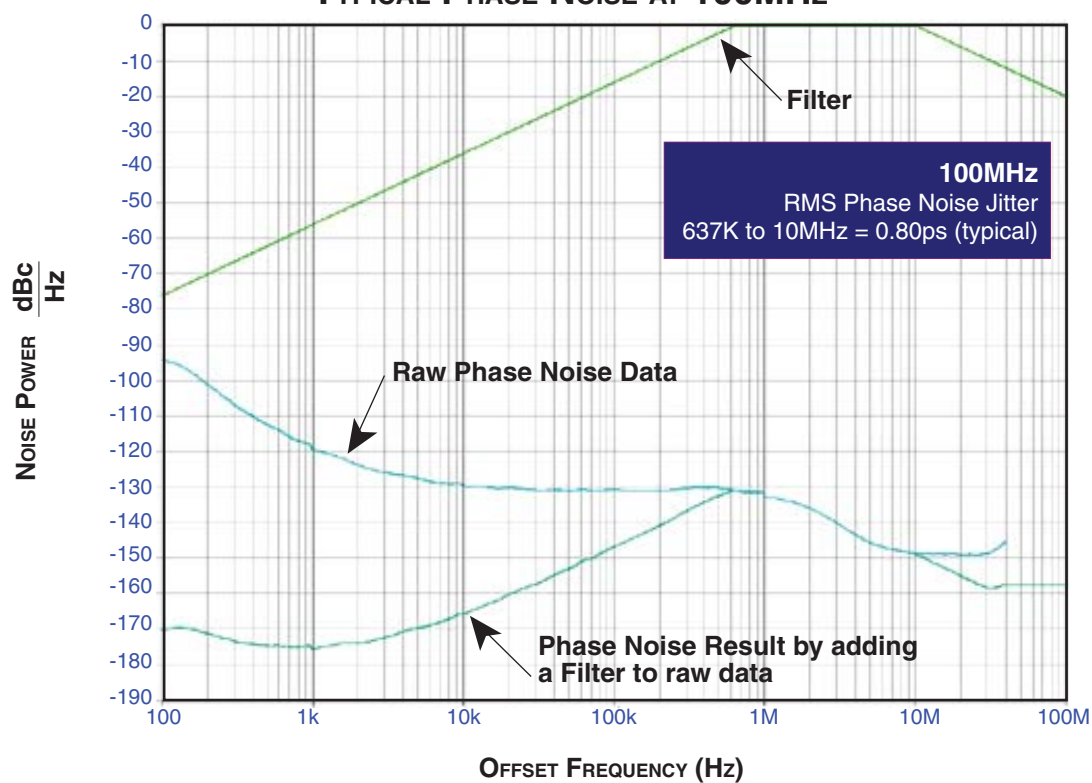
Parameter	Test Conditions	Minimum	Typical	Maximum	Units
Mode of Oscillation		Fundamental			
Frequency		25		26.5625	MHz
Equivalent Series Resistance (ESR)				50	Ω
Shunt Capacitance				7	pF

TABLE 5. AC CHARACTERISTICS, $V_{CC} = 3.3V \pm 5\%$, $T_A = -40^\circ\text{C}$ TO 85°C

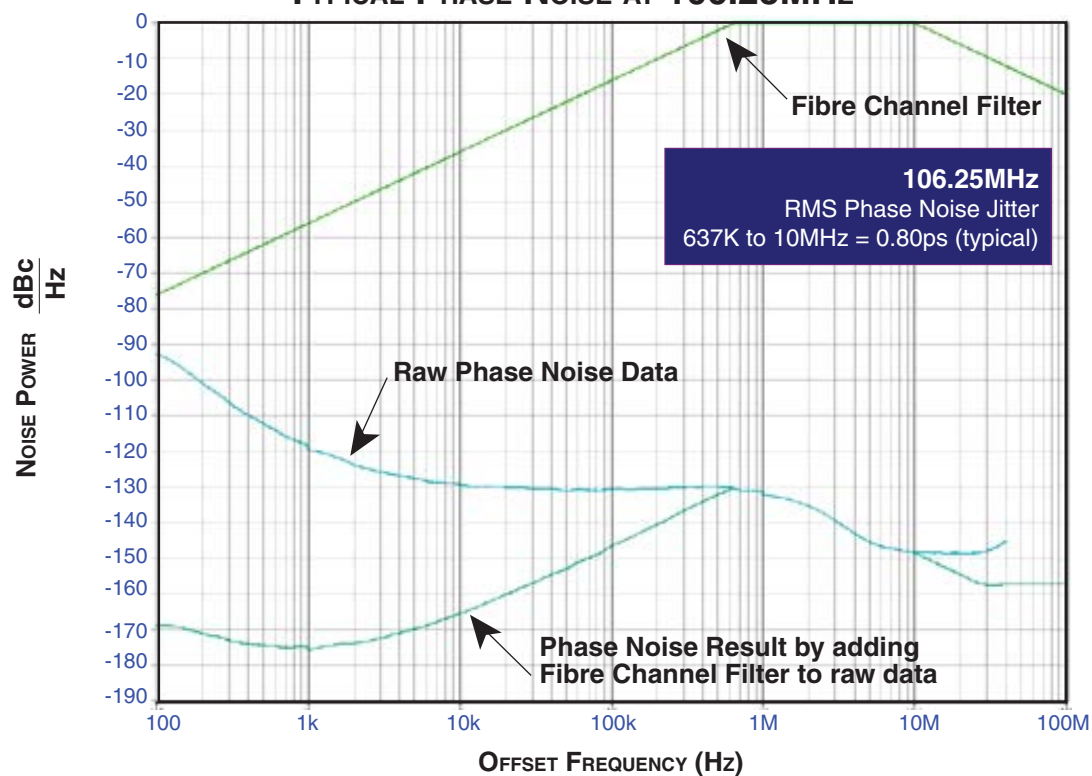
Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
F_{OUT}	Output Frequency		93.33		113.33	MHz
$t_{jit}(\emptyset)$	RMS Phase Jitter (Random); NOTE 1	106.25MHz; Integration Range: 637KHz - 10MHz		0.80		ps
		100MHz; Integration Range: 637KHz - 10MHz		0.80		ps
t_R / t_F	Output Rise/Fall Time	20% to 80%	300		600	ps
odc	Output Duty Cycle		48		52	%

NOTE 1: Please refer to the Phase Noise Plot.

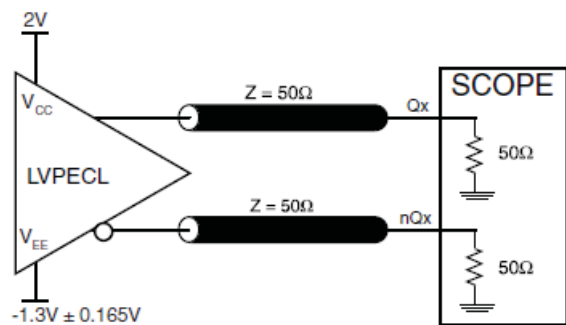
TYPICAL PHASE NOISE AT 100MHz



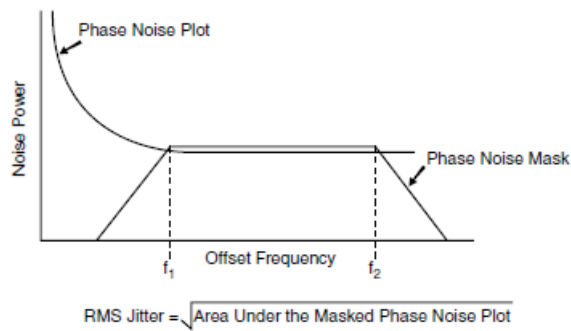
TYPICAL PHASE NOISE AT 106.25MHz



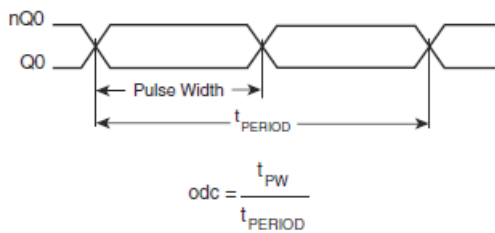
PARAMETER MEASUREMENT INFORMATION



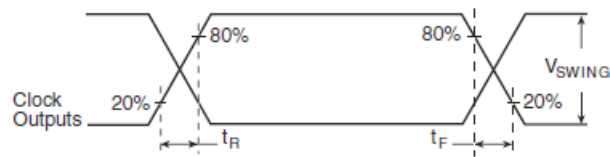
3.3V OUTPUT LOAD AC TEST CIRCUIT



RMS PHASE JITTER



OUTPUT DUTY CYCLE/PULSE WIDTH/PERIOD



OUTPUT RISE/FALL TIME

APPLICATION INFORMATION

POWER SUPPLY FILTERING TECHNIQUES

As in any high speed analog circuitry, the power supply pins are vulnerable to random noise. The 843011 provides separate power supplies to isolate any high switching noise from the outputs to the internal PLL. V_{CC} , and V_{CCA} should be individually connected to the power supply plane through vias, and bypass capacitors should be used for each pin. To achieve optimum jitter performance, power supply isolation is required. *Figure 1* illustrates how a 10Ω resistor along with a $10\mu\text{F}$ and a $.01\mu\text{F}$ bypass capacitor should be connected to each V_{CCA} pin.

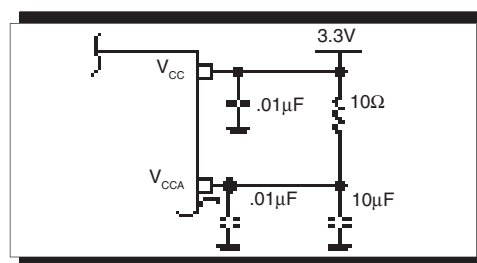


FIGURE 1. POWER SUPPLY FILTERING

CRYSTAL INPUT INTERFACE

The 843011 has been characterized with 18pF parallel resonant crystals. The capacitor values, C1 and C2, shown in *Figure 2* below were determined using a 26.5625MHz, 18pF

parallel resonant crystal and were chosen to minimize the ppm error. The optimum C1 and C2 values can be slightly adjusted for different board layouts.

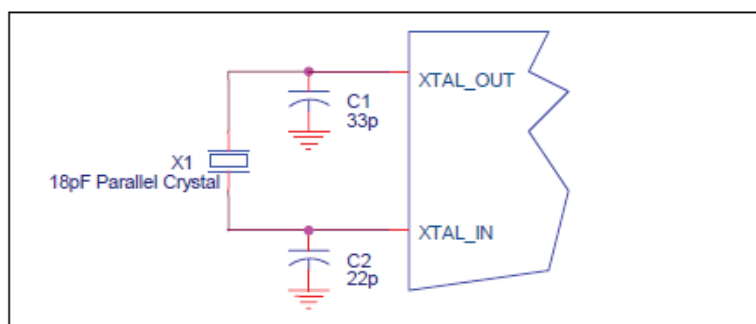


Figure 2. CRYSTAL INPUT INTERFACE

POWER CONSIDERATIONS

This section provides information on power dissipation and junction temperature for the 843011. Equations and example calculations are also provided.

1. Power Dissipation.

The total power dissipation for the 843011 is the sum of the core power plus the power dissipated in the load(s). The following is the power dissipation for $V_{CC} = 3.3V + 5\% = 3.465V$, which gives worst case results.

NOTE: Please refer to Section 3 for details on calculating power dissipated in the load.

- Power (core)_{MAX} = $V_{CC_MAX} * I_{EE_MAX} = 3.465V * 93mA = 322.2mW$
- Power (outputs)_{MAX} = **30mW/Loaded Output pair**

$$\text{Total Power}_{MAX} (3.465V, \text{ with all outputs switching}) = 322.2mW + 30mW = 352.2mW$$

2. Junction Temperature.

Junction temperature, T_J , is the temperature at the junction of the bond wire and bond pad and directly affects the reliability of the device. The maximum recommended junction temperature for the devices is 125°C.

The equation for T_J is as follows: $T_J = \theta_{JA} * Pd_total + T_A$

T_J = Junction Temperature

θ_{JA} = Junction-to-Ambient Thermal Resistance

Pd_total = Total Device Power Dissipation (example calculation is in section 1 above)

T_A = Ambient Temperature

In order to calculate junction temperature, the appropriate junction-to-ambient thermal resistance θ_{JA} must be used. Assuming a moderate air flow of 1 meter per second and a multi-layer board, the appropriate value is 90.5°C/W per Table 6 below.

Therefore, T_J for an ambient temperature of 85°C with all outputs switching is:

$$85^\circ C + 0.352W * 90.5^\circ C/W = 116.9^\circ C. \text{ This is below the limit of } 125^\circ C.$$

This calculation is only an example. T_J will obviously vary depending on the number of loaded outputs, supply voltage, air flow, and the type of board (single layer or multi-layer).

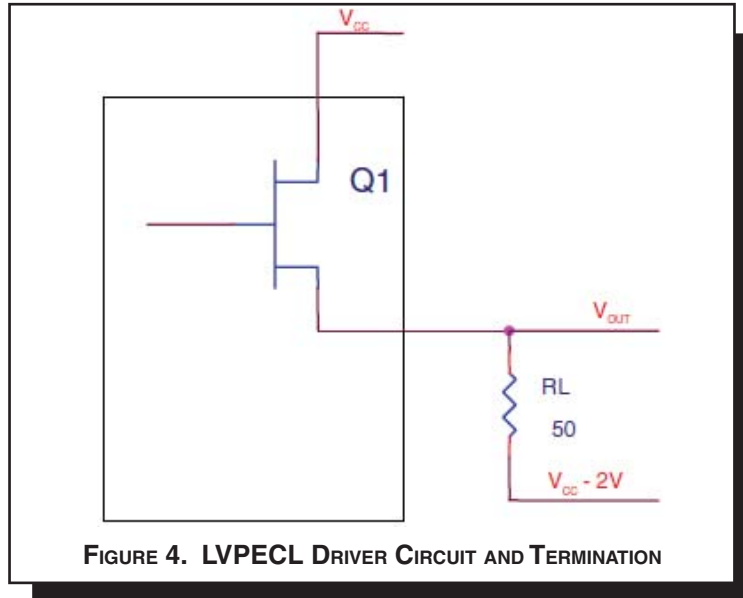
TABLE 6. THERMAL RESISTANCE θ_{JA} FOR 8-PIN TSSOP, FORCED CONVECTION

θ_{JA} by Velocity (Meters per Second)			
	0	1	2.5
Multi-Layer PCB, JEDEC Standard Test Boards	101.7°C/W	90.5°C/W	89.8°C/W

3. Calculations and Equations.

The purpose of this section is to derive the power dissipated into the load.

LVPECL output driver circuit and termination are shown in Figure 4.



To calculate worst case power dissipation into the load, use the following equations which assume a 50Ω load, and a termination voltage of $V_{CC} - 2V$.

- For logic high, $V_{OUT} = V_{OH_MAX} = V_{CC_MAX} - 0.9V$

$$(V_{CCO_MAX} - V_{OH_MAX}) = 0.9V$$

- For logic low, $V_{OUT} = V_{OL_MAX} = V_{CC_MAX} - 1.7V$

$$(V_{CCO_MAX} - V_{OL_MAX}) = 1.7V$$

Pd_H is power dissipation when the output drives high.

Pd_L is the power dissipation when the output drives low.

$$Pd_H = [(V_{OH_MAX} - (V_{CC_MAX} - 2V))/R_L] * (V_{CC_MAX} - V_{OH_MAX}) = [(2V - (V_{CC_MAX} - V_{OH_MAX}))/R_L] * (V_{CC_MAX} - V_{OH_MAX}) = [(2V - 0.9V)/50\Omega] * 0.9V = 19.8mW$$

$$Pd_L = [(V_{OL_MAX} - (V_{CC_MAX} - 2V))/R_L] * (V_{CC_MAX} - V_{OL_MAX}) = [(2V - (V_{CC_MAX} - V_{OL_MAX}))/R_L] * (V_{CC_MAX} - V_{OL_MAX}) = [(2V - 1.7V)/50\Omega] * 1.7V = 10.2mW$$

$$\text{Total Power Dissipation per output pair} = Pd_H + Pd_L = 30mW$$

RELIABILITY INFORMATION

TABLE 7. θ_{JA} VS. AIR FLOW TABLE FOR 8 LEAD TSSOP

θ_{JA} by Velocity (Meters per Second)			
	0	1	2.5
Multi-Layer PCB, JEDEC Standard Test Boards	101.7°C/W	90.5°C/W	89.8°C/W

TRANSISTOR COUNT

The transistor count for 843011 is: 2436

PACKAGE OUTLINE - G SUFFIX FOR 8 LEAD TSSOP

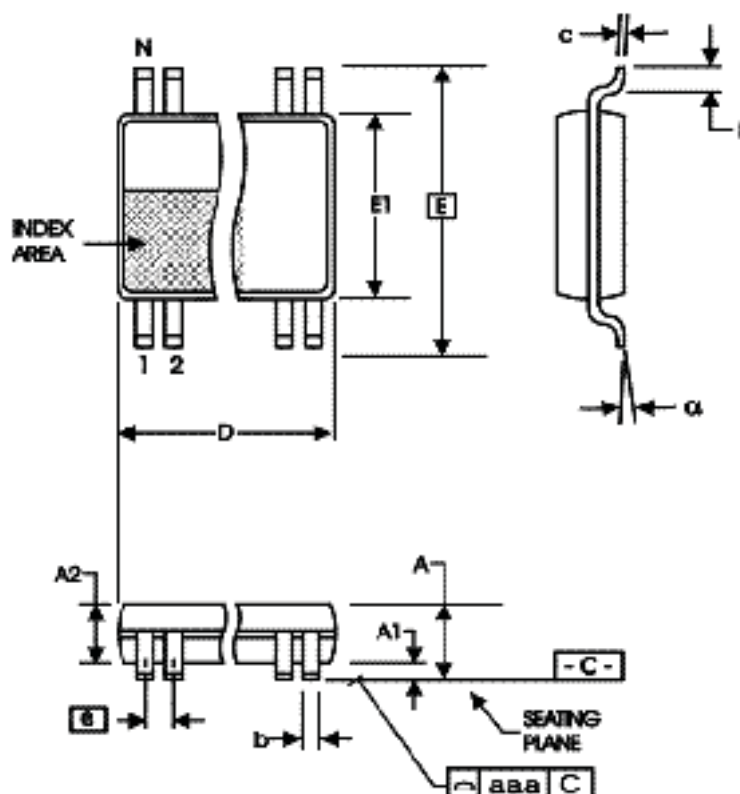


TABLE 8. PACKAGE DIMENSIONS

SYMBOL	Millimeters	
	Minimum	Maximum
N	8	
A	--	1.20
A1	0.05	0.15
A2	0.80	1.05
b	0.19	0.30
c	0.09	0.20
D	2.90	3.10
E	6.40 BASIC	
E1	4.30	4.50
e	0.65 BASIC	
L	0.45	0.75
α	0°	8°
aaa	--	0.10

Reference Document: JEDEC Publication 95, MO-153

TABLE 9. ORDERING INFORMATION

Part/Order Number	Marking	Package	Shipping Package	Temperature
843011AGLF	011AL	8 lead "Lead-Free" TSSOP	tube	-40°C to 85°C
843011AGLFT	011AL	8 lead "Lead-Free" TSSOP	tape & reel	-40°C to 85°C

NOTE: Parts that are ordered with an "LF" suffix to the part number are the Pb-Free configuration and are RoHS compliant.

REVISION HISTORY SHEET				
Rev	Table	Page	Description of Change	Date
B	3A	3	Power Supply DC Characteristics Table - added I_{CCA} spec.	8/23/04
B	T9	12	Ordering Information Table - corrected count from 154 to 100.	10/13/04
B	T9	12	Ordering Information Table - corrected Lead-Free marking from 3011AL to 011AL.	10/20/04
B		1 6 7	Changed ambient operating temperature bullet from -30°C to 85°C to -40°C to 85°C and throughout data sheet. Crystal Input Interface - changed capacitor C2 value from 27p to 22p. Application Schematic - corrected schematic to reflect Crystal Input Interface change.	12/10/04
B	T9	12	Ordering Information Table - deleted tube count in Shipping Packaging column.	1/26/07
B	T9	12 14	Updated datasheet's header/footer with IDT from ICS. Removed ICS prefix from Part/Order Number column. Added Contact Page.	7/26/10
B	T9	12	Ordering Information - removed leaded devices. Updated data sheet format.	9/25/15

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